

**HERMETIC POWER SCHOTTKY RECTIFIER**  
**Very Low Forward Voltage Drop**  
**Ultra Low Reverse Leakage**  
**200°C Operating Temperature**

**Applications:**

· Switching Power Supply · Converters · Free-Wheeling Diodes · Polarity Protection Diode

**Features:**

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Ultra Low Reverse Leakage
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Out Performs 100 Volt Ultrafast Rectifiers

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	100	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form	15	A
Max. Peak One Cycle Non-Repetitive Surge Current	$I_{FSM}$	8.3 ms, half Sine wave	75	A
Non-Repetitive Avalanche Energy	$E_{AS}$	$T_J = 25\text{ }^\circ\text{C}$ , $I_{AS} = 0.53\text{ A}$ , $L = 56\text{ mH}$	8.0	mJ
Repetitive Avalanche Current	$I_{AR}$	$I_{AS}$ decay linearly to 0 in 1 $\mu\text{s}$ $f$ limited by $T_J$ max $V_A=1.5V_R$	0.53	A
Max. Thermal Resistance	$R_{\theta JC}$	(per leg)	2.1	$^\circ\text{C/W}$
Max. Junction Temperature	$T_J$	-	-65 to +200	$^\circ\text{C}$
Max. Storage Temperature	$T_{stg}$	-	-65 to +200	$^\circ\text{C}$

**Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 15A, Pulse, $T_J = 25\text{ }^\circ\text{C}$ (per leg)	0.93	V
	$V_{F2}$	@ 15A, Pulse, $T_J = 125\text{ }^\circ\text{C}$ (per leg)	0.77	V
Max. Reverse Current	$I_{R1}$	@ $V_R = 100\text{V}$ , Pulse, $T_J = 25\text{ }^\circ\text{C}$ (per leg)	0.35	mA
	$I_{R2}$	@ $V_R = 100\text{V}$ , Pulse, $T_J = 125\text{ }^\circ\text{C}$ (per leg)	8.0	mA
Max. Junction Capacitance	$C_T$	@ $V_R = 5\text{V}$ , $T_C = 25\text{ }^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$ , $V_{SIG} = 50\text{mV}$ (p-p) (per leg)	500	pF



**TECHNICAL DATA**

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